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FCA20N60 N-Channel SuperFET[®] MOSFET 600 V, 20 A, 190 mΩ

Features

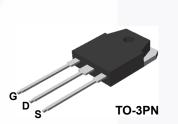
- 650V @ T_{.I} = 150°C
- Typ. R_{DS(on)} = 150 mΩ
- Ultra Low Gate Charge (Typ. Q_g = 75 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 165 pF)
- 100% Avalanche Tested

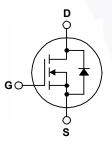
Applications

- Solar Inverter
- AC-DC Power Supply

Description

SuperFET[®] MOSFET is Fairchild Semiconductor's first generation of high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low onresistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.





MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		FCA20N60 / FCA20N60_F109	Unit V			
V _{DSS}	Drain to Source Voltage			600		
V _{GSS}	Gate-Soure voltage			±30	V	
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		20	A	
	Drain Current	- Continuous (T _C = 100 ^o C)		12.5		
I _{DM}	Drain Current	- Pulsed	(Note 1)	60	Α	
E _{AS}	Single Pulsed Avalanche	Energy	(Note 2)	690	mJ	
I _{AR}	Avalanche Current		(Note 1)	20	Α	
E _{AR}	Repetitive Avalanche Ene	ergy	(Note 1)	20.8	mJ	
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5	V/ns	
P _D	Dewer Dissignation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		208	W	
	Power Dissipation	- Derate Above 25°C	- Derate Above 25°C			
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C	

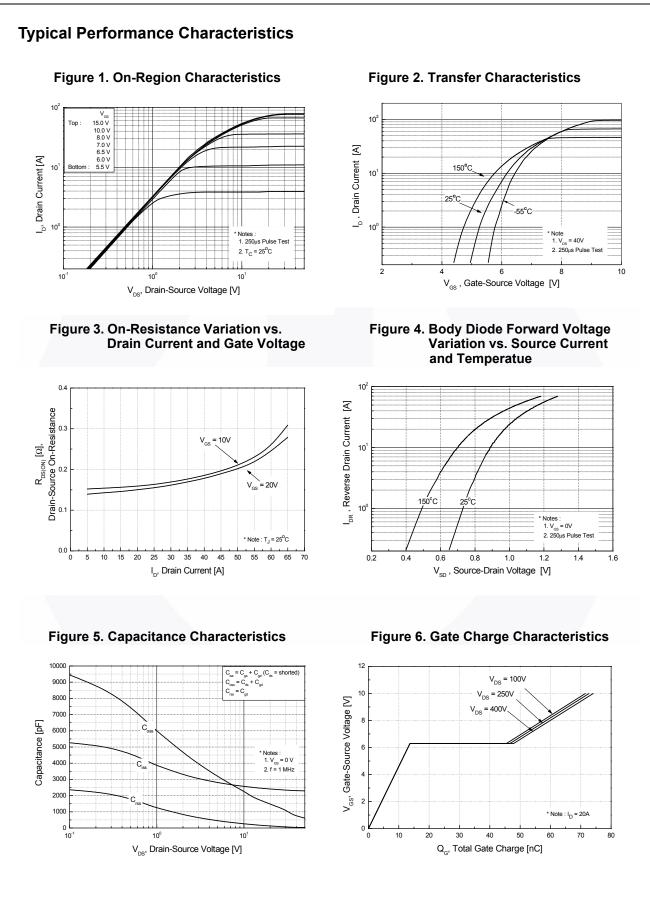
Thermal Characteristics

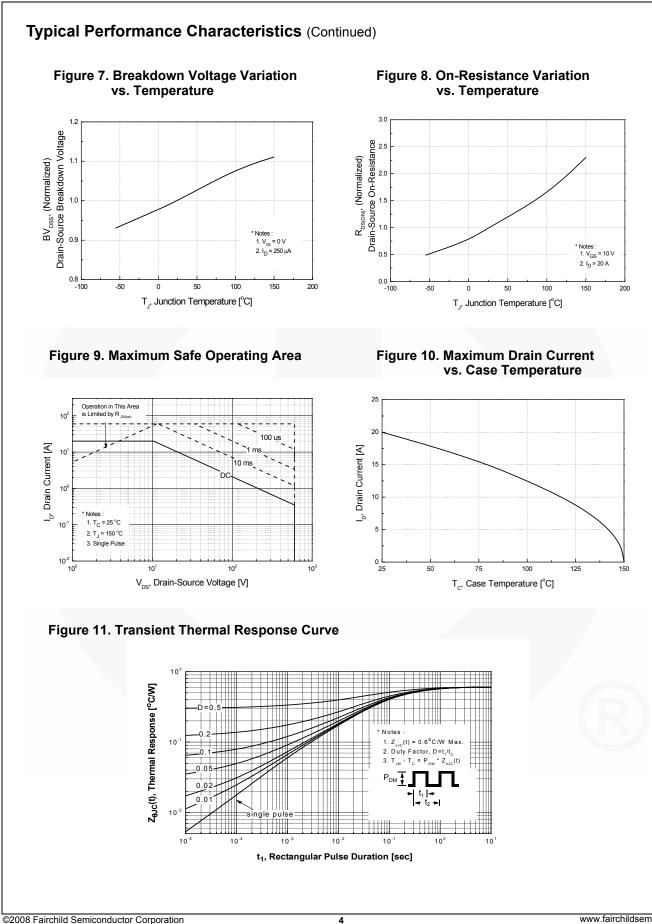
Symbol	Parameter	FCA20N60 / FCA20N60_F109	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.6	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient, Max.	41.7	°C/VV

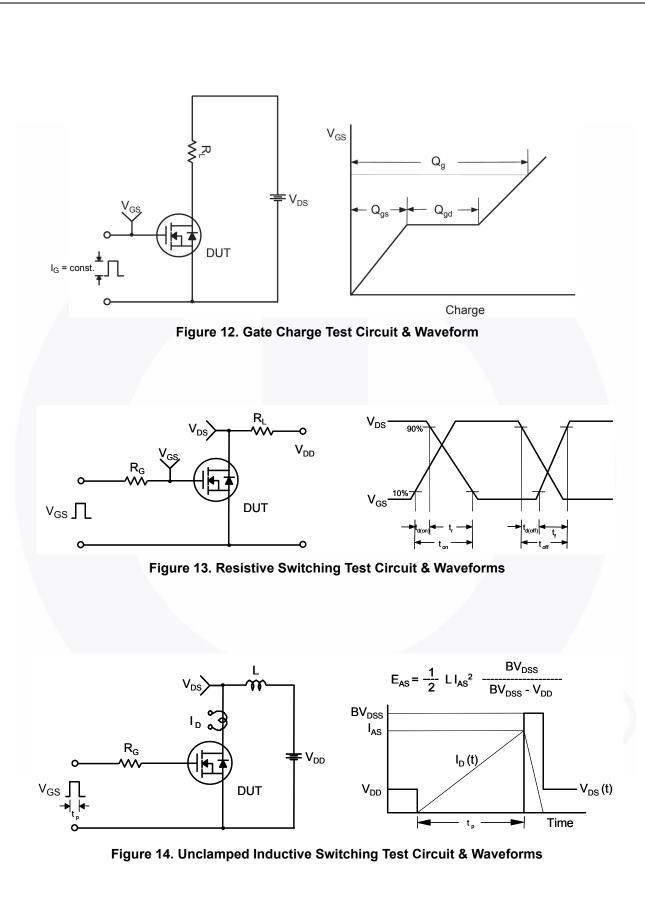
Part Number		Top Mark	Pac	kage	Packing Method	Reel Size	Тар	e Width	Qua	ntity
FCA20	N60	FCA20N60	TO-	3PN	Tube	N/A	N/A		30 units	
FCA20N60_F109 FCA20N60 TC		TO-	-3PN Tube N/A		N/A		30 units			
Electrica	al Char	acteristics T _C =	25ºC un	ess otł	nerwise noted.					
Symbol		Parameter			Test Conditio	ons	Min.	Тур.	Max.	Uni
Off Chara	cteristic	S								
			I _D = 250 μA, V _{GS} = 0 V, T _J = 25 ^o C			600	-	-	V	
BV _{DSS}			tage		$I_D = 250 \ \mu$ A, $V_{GS} = 0 \ V$, $T_J = 150^{\circ}$ C			650	-	V
ΔBV _{DSS} / ΔT _J		Breakdown Voltage Temperature Coefficient			$I_D = 250 \ \mu\text{A}$, Referenced to 25°C			0.6	-	V/ºC
BV _{DS}		Drain-Source Avalanche Breakdown Voltage			V _{GS} = 0 V, I _D = 20 A			700	-	v
DSS	Zero G	te Voltage Drain Current			V _{DS} = 600 V, V _{GS} = 0 V		-	-	1	μA
055					_{DS} = 480 V, T _C = 125 ^o		-	-	10	μι
GSS	Gate to	Gate to Body Leakage Current			$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$			-	±100	nA
On Chara	cteristic	s								
V _{GS(th)}	Gate T	e Threshold Voltage		V	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$			-	5.0	V
R _{DS(on)}	Static D	Static Drain to Source On Resistance		V	V _{GS} = 10 V, I _D = 10 A			0.15	0.19	Ω
JFS	Forward Transconductance			V	V _{DS} = 40 V, I _D = 10 A			17	-	S
Dynamic (Characte	eristics								
C _{iss}	1	apacitance					-	2370	3080	pF
C _{oss}	Output	Output Capacitance Reverse Transfer Capacitance			V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		-	1280	1665	pF
Srss	Reverse						-	95	-	pF
C _{oss}	Output Capacitance		V	V_{DS} = 480 V, V_{GS} = 0 V, f = 1 MHz			65	85	pF	
Coss(eff.)	Effectiv	e Output Capacitance		V	$V_{DS} = 0 V$ to 400 V, $V_{GS} = 0 V$		-	165	-	pF
λ ^g	Total Ga	Total Gate Charge at 10V		V	V _{DS} = 480 V, I _D = 20 A,		-	75	98	nC
2 _{gs}	Gate to Source Gate Charge			$V_{GS} = 10 V$		-	13.5	18	nC	
Q _{gd}	Gate to	Gate to Drain "Miller" Charge			(Note 4)		-	36	-	nC
Switching	Charac	teristics								
d(on)		Delay Time					7.	62	135	ns
r		n Rise Time		V _{DD} = 300 V, I _D = 20 A,			-	140	290	ns
d(off)		f Delay Time		V	$V_{GS} = 10 \text{ V}, \text{ R}_{G} = 25 \Omega$ (Note 4)		_	230	470	ns
f		f Fall Time					-	65	140	ns
		de Characteristics		iode Er	onward Current		-		20	A
<u>s</u>		mum Pulsed Drain to Source Diode Fo					-		60	A
sм / _{SD}		n to Source Diode Forward Voltage			$V_{GS} = 0 V, I_{SD} = 20 A$			-	1.4	V
		Recovery Time	tonage	$V_{GS} = 0 V, I_{SD} = 20 A$ $V_{GS} = 0 V, I_{SD} = 20 A,$ $dI_F/dt = 100 A/\mu s$			-	530	-	ns
<u>m</u>		Recovery Charge				-	10.5	-	μC	
ସ _{rr}	I COVEI SE	recovery charge		u	F. at 100 / vµb		-	10.0		μυ

JSD ≥ 20 A, dirut ≥ 200 A/µs, VDD ≤ BVDSS, starting 1 J = 25°C.
4: Essentially independent of operating temperature typical characteristics.

FCA20N60 — N-Channel SuperFET[®] MOSFET

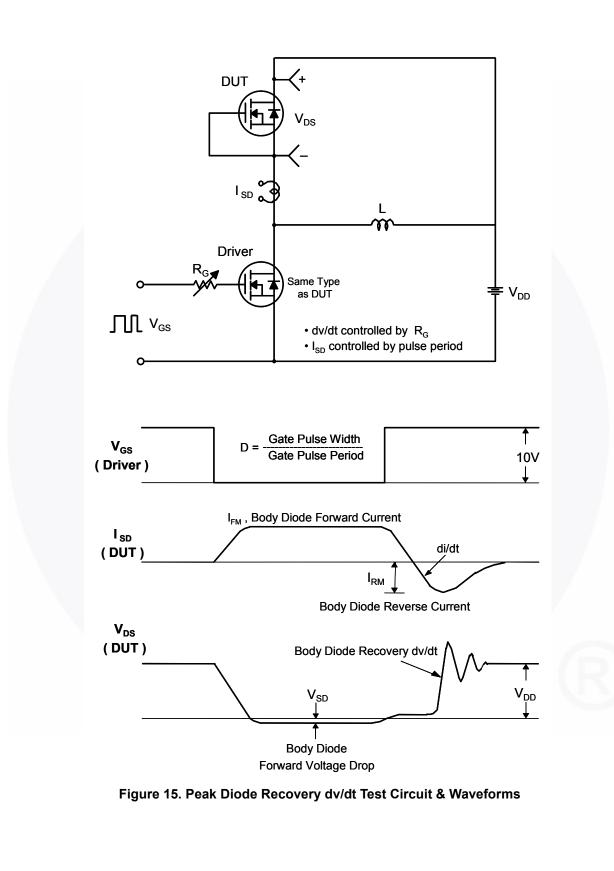


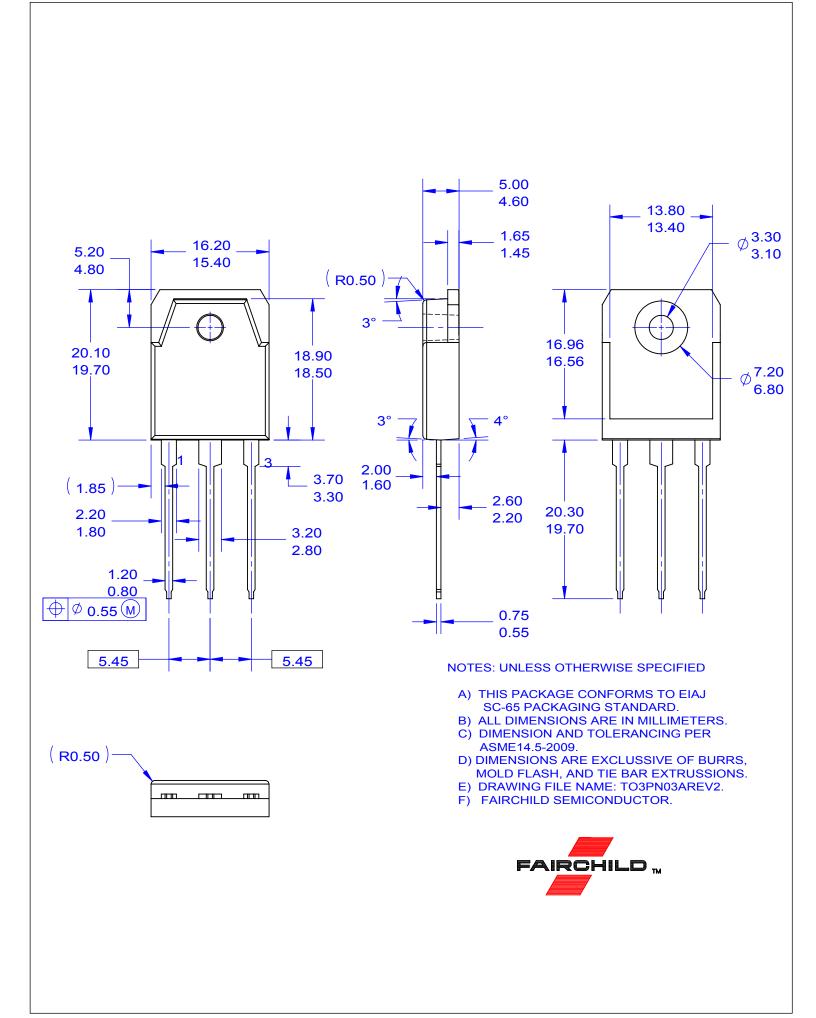




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